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Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details

Product Status	Obsolete
Core Processor	PowerPC e500
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	1.333GHz
Co-Processors/DSP	Signal Processing; SPE
RAM Controllers	DDR, DDR2, SDRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100/1000Mbps (4)
SATA	-
USB	-
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	783-BBGA, FCBGA
Supplier Device Package	783-FCBGA (29x29)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8547vuauj

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Overview



Figure 1. Device Block Diagram

1.1 Key Features

The following list provides an overview of the device feature set:

- High-performance 32-bit core built on Power Architecture® technology.
 - 32-Kbyte L1 instruction cache and 32-Kbyte L1 data cache with parity protection. Caches can be locked entirely or on a per-line basis, with separate locking for instructions and data.
 - Signal-processing engine (SPE) APU (auxiliary processing unit). Provides an extensive instruction set for vector (64-bit) integer and fractional operations. These instructions use both the upper and lower words of the 64-bit GPRs as they are defined by the SPE APU.
 - Double-precision floating-point APU. Provides an instruction set for double-precision (64-bit) floating-point instructions that use the 64-bit GPRs.
 - 36-bit real addressing
 - Embedded vector and scalar single-precision floating-point APUs. Provide an instruction set for single-precision (32-bit) floating-point instructions.
 - Memory management unit (MMU). Especially designed for embedded applications. Supports 4-Kbyte to 4-Gbyte page sizes.
 - Enhanced hardware and software debug support

5 **RESET** Initialization

This section describes the AC electrical specifications for the RESET initialization timing requirements of the device. The following table provides the RESET initialization AC timing specifications for the DDR SDRAM component(s).

Parameter/Condition	Min	Max	Unit	Notes
Required assertion time of HRESET	100	—	μS	—
Minimum assertion time for SRESET	3	—	SYSCLKs	1
PLL input setup time with stable SYSCLK before HRESET negation	100	—	μS	—
Input setup time for POR configs (other than PLL config) with respect to negation of HRESET	4	—	SYSCLKs	1
Input hold time for all POR configs (including PLL config) with respect to negation of HRESET	2	—	SYSCLKs	1
Maximum valid-to-high impedance time for actively driven POR configs with respect to negation of HRESET	—	5	SYSCLKs	1

Table 8. RESE1	Initialization	Timing	Specifications
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Note:

1. SYSCLK is the primary clock input for the device.

The following table provides the PLL lock times.

Table 9. PLL Lock Times

Parameter/Condition	Min	Мах	Unit
Core and platform PLL lock times	—	100	μS
Local bus PLL lock time	—	50	μS
PCI/PCI-X bus PLL lock time	—	50	μS

5.1 Power-On Ramp Rate

This section describes the AC electrical specifications for the power-on ramp rate requirements.

Controlling the maximum power-on ramp rate is required to avoid falsely triggering the ESD circuitry. The following table provides the power supply ramp rate specifications.

Table 10.	Power	Supply	Ramp	Rate
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Parameter	Min	Мах	Unit	Notes
Required ramp rate for MVREF	—	3500	V/s	1
Required ramp rate for VDD	_	4000	V/s	1, 2

Note:

1. Maximum ramp rate from 200 to 500 mV is most critical as this range may falsely trigger the ESD circuitry.

2. VDD itself is not vulnerable to false ESD triggering; however, as per Section 22.2, "PLL Power Supply Filtering," the recommended AVDD_CORE, AVDD_PLAT, AVDD_LBIU, AVDD_PCI1 and AVDD_PCI2 filters are all connected to VDD. Their ramp rates must be equal to or less than the VDD ramp rate.

DDR and DDR2 SDRAM

Table 19. DDR SDRAM Output AC Timing Specifications (continued)

At recommended operating conditions.

Parameter	Symbol ¹	Min	Мах	Unit	Notes
MDQS epilogue end	t _{DDKHME}	-0.6	0.6	ns	6

Notes:

- The symbols used for timing specifications follow the pattern of t_{(first two letters of functional block)(signal)(state)(reference)(state)} for inputs and t_(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. Output hold time can be read as DDR timing (DD) from the rising or falling edge of the reference clock (KH or KL) until the output went invalid (AX or DX). For example, t_{DDKHAS} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes from the high (H) state until outputs (A) are setup (S) or output valid time. Also, t_{DDKLDX} symbolizes DDR timing (DD) for the time t_{MCK} memory clock reference (K) goes low (L) until data outputs (D) are invalid (X) or data output hold time.
- 2. All MCK/MCK referenced measurements are made from the crossing of the two signals ±0.1 V.
- 3. ADDR/CMD includes all DDR SDRAM output signals except MCK/MCK, MCS, and MDQ/MECC/MDM/MDQS.
- 4. Note that t_{DDKHMH} follows the symbol conventions described in note 1. For example, t_{DDKHMH} describes the DDR timing (DD) from the rising edge of the MCK[n] clock (KH) until the MDQS signal is valid (MH). t_{DDKHMH} can be modified through control of the MDQS override bits (called WR_DATA_DELAY) in the TIMING_CFG_2 register. This is typically set to the same delay as in DDR_SDRAM_CLK_CNTL[CLK_ADJUST]. The timing parameters listed in the table assume that these 2 parameters have been set to the same adjustment value. See the MPC8548E PowerQUICC III Integrated Processor Reference Manual for a description and understanding of the timing modifications enabled by use of these bits.
- Determined by maximum possible skew between a data strobe (MDQS) and any corresponding bit of data (MDQ), ECC (MECC), or data mask (MDM). The data strobe must be centered inside of the data eye at the pins of the microprocessor.
- 6. All outputs are referenced to the rising edge of MCK[*n*] at the pins of the microprocessor. Note that t_{DDKHMP} follows the symbol conventions described in note 1.

NOTE

For the ADDR/CMD setup and hold specifications in Table 19, it is assumed that the clock control register is set to adjust the memory clocks by 1/2 applied cycle.

Figure 3 shows the DDR SDRAM output timing for the MCK to MDQS skew measurement (t_{DDKHMH}).







Figure 25. Local Bus Signals, GPCM/UPM Signals for LCCR[CLKDIV] = 4 (PLL Enabled)

PCI/PCI-X

Table 54. PCI-X AC Timing Specifications at 133 MHz (continued)

Parameter	Symbol	Min	Max	Unit	Notes
HRESET to PCI-X initialization pattern hold time	t _{PCRHIX}	0	50	ns	6, 12

Notes:

1. See the timing measurement conditions in the PCI-X 1.0a Specification.

- 2. Minimum times are measured at the package pin (not the test point). Maximum times are measured with the test point and load circuit.
- 3. Setup time for point-to-point signals applies to REQ and GNT only. All other signals are bused.
- 4. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- 5. Setup time applies only when the device is not driving the pin. Devices cannot drive and receive signals at the same time.
- 6. Maximum value is also limited by delay to the first transaction (time for HRESET high to first configuration access, t_{PCRHFV}). The PCI-X initialization pattern control signals after the rising edge of HRESET must be negated no later than two clocks before the first FRAME and must be floated no later than one clock before FRAME is asserted.
- 7. A PCI-X device is permitted to have the minimum values shown for t_{PCKHOV} and t_{CYC} only in PCI-X mode. In conventional mode, the device must meet the requirements specified in PCI 2.2 for the appropriate clock frequency.

8. Device must meet this specification independent of how many outputs switch simultaneously.

9. The timing parameter t_{PCIVKH} is a minimum of 1.4 ns rather than the minimum of 1.2 ns in the PCI-X 1.0a Specification.

- 10. The timing parameter t_{PCRHFV} is a minimum of 10 clocks rather than the minimum of 5 clocks in the *PCI-X 1.0a Specification.*
- 11. Guaranteed by characterization.

12. Guaranteed by design.

of a balanced interchange circuit and ground. In this example, for SerDes output, $V_{cm_out} = V_{SD_TX} + V_{\overline{SD}_TX} = (A + B)/2$, which is the arithmetic mean of the two complimentary output voltages within a differential pair. In a system, the common mode voltage may often differ from one component's output to the other's input. Sometimes, it may be even different between the receiver input and driver output circuits within the same component. It is also referred to as the DC offset.



To illustrate these definitions using real values, consider the case of a CML (current mode logic) transmitter that has a common mode voltage of 2.25 V and each of its outputs, TD and TD, has a swing that goes between 2.5 and 2.0 V. Using these values, the peak-to-peak voltage swing of each signal (TD or TD) is 500 mVp-p, which is referred as the single-ended swing for each signal. In this example, since the differential signaling environment is fully symmetrical, the transmitter output's differential swing (V_{OD}) has the same amplitude as each signal's single-ended swing. The differential output signal ranges between 500 and -500 mV, in other words, V_{OD} is 500 mV in one phase and -500 mV in the other phase. The peak differential voltage (V_{DIFFp}) is 500 mV. The peak-to-peak differential voltage (V_{DIFFp}) is 1000 mVp-p.

16.2 SerDes Reference Clocks

The SerDes reference clock inputs are applied to an internal PLL whose output creates the clock used by the corresponding SerDes lanes. The SerDes reference clocks inputs are SD_REF_CLK and SD_REF_CLK for PCI Express and serial RapidIO.

The following sections describe the SerDes reference clock requirements and some application information.

16.2.1 SerDes Reference Clock Receiver Characteristics

Figure 39 shows a receiver reference diagram of the SerDes reference clocks.

- The supply voltage requirements for $XV_{DD SRDS2}$ are specified in Table 1 and Table 2.
- SerDes Reference clock receiver reference circuit structure:

Symbol	Parameter	Min	Nom	Max	Unit	Comments
UI	Unit interval	399.88	400	400.12	ps	Each UI is 400 ps \pm 300 ppm. UI does not account for spread spectrum clock dictated variations. See Note 1.
V _{TX-DIFFp-p}	Differential peak-to-peak output voltage	0.8	_	1.2	V	$V_{TX-DIFFp-p} = 2 \times V_{TX-D+} - V_{TX-D-} $. See Note 2.
V _{TX-DE-RATIO}	De-emphasized differential output voltage (ratio)	-3.0	-3.5	-4.0	dB	Ratio of the $V_{TX-DIFFp-p}$ of the second and following bits after a transition divided by the $V_{TX-DIFFp-p}$ of the first bit after a transition. See Note 2.
T _{TX-EYE}	Minimum TX eye width	0.70	_	_	UI	The maximum transmitter jitter can be derived as $T_{TX-MAX-JITTER} = 1 - T_{TX-EYE} = 0.3$ UI. See Notes 2 and 3.
T _{TX-EYE-MEDIAN-to-} MAX-JITTER	Maximum time between the jitter median and maximum deviation from the median.	_	_	0.15	UI	Jitter is defined as the measurement variation of the crossing points ($V_{TX-DIFFp-p} = 0$ V) in relation to a recovered TX UI. A recovered TX UI is calculated over 3500 consecutive unit intervals of sample data. Jitter is measured using all edges of the 250 consecutive UI in the center of the 3500 UI used for calculating the TX UI. See Notes 2 and 3.
T _{TX-RISE} , T _{TX-FALL}	D+/D-TX output rise/fall time	0.125	_	—	UI	See Notes 2 and 5.
V _{TX-CM-ACp}	RMS AC peak common mode output voltage	_	_	20	mV	$\begin{split} & V_{TX\text{-}CM\text{-}ACp} = RMS(V_{TXD\text{+}} + V_{TXD\text{-}} /2 - V_{TX\text{-}CM\text{-}DC}) \\ & V_{TX\text{-}CM\text{-}DC} = DC_{(avg)} \text{ of } V_{TX\text{-}D\text{+}} + V_{TX\text{-}D\text{-}} /2. \\ & See Note 2. \end{split}$
V _{TX-CM-DC-ACTIVE-} IDLE-DELTA	Absolute delta of dc common mode voltage during L0 and electrical idle	0	_	100	mV	$\begin{split} V_{TX-CM-DC} & (during \ L0) + V_{TX-CM-Idle-DC} & (during \\ electrical \ idle) &\leq 100 \ mV \\ V_{TX-CM-DC} &= DC_{(avg)} \ of \ V_{TX-D+} + V_{TX-D-} /2 \ [L0] \\ V_{TX-CM-Idle-DC} &= DC_{(avg)} \ of \ V_{TX-D+} + V_{TX-D-} /2 \\ [electrical \ idle] \\ See \ Note \ 2. \end{split}$
VTX-CM-DC-LINE-DELTA	Absolute delta of DC common mode between D+ and D–	0		25	mV	$\begin{split} V_{TX-CM-DC-D+} - V_{TX-CM-DC-D-} &\leq 25 \text{ mV} \\ V_{TX-CM-DC-D+} &= DC_{(avg)} \text{ of } V_{TX-D+} \\ V_{TX-CM-DC-D-} &= DC_{(avg)} \text{ of } V_{TX-D-} . \\ \text{See Note 2.} \end{split}$
V _{TX} -IDLE-DIFFp	Electrical idle differential peak output voltage	0	_	20	mV	$\begin{split} & V_{\text{TX-IDLE-DIFFp}} = V_{\text{TX-IDLE-D+}} - V_{\text{TX-IDLE-D-}} \\ & \leq 20 \text{ mV.} \\ & \text{See Note 2.} \end{split}$
V _{TX-RCV-DETECT}	The amount of voltage change allowed during receiver detection			600	mV	The total amount of voltage change that a transmitter can apply to sense whether a low impedance receiver is present. See Note 6.

Table 57. Differential Receiver (RX) Input Specifications (continued)

Symbol	Parameter	Min	Nom	Max	Unit	Comments
L _{TX-SKEW}	Total Skew			20	ns	Skew across all lanes on a Link. This includes variation in the length of SKP ordered set (for example, COM and one to five symbols) at the RX as well as any delay differences arising from the interconnect itself.

Notes:

- 1. No test load is necessarily associated with this value.
- 2. Specified at the measurement point and measured over any 250 consecutive UIs. The test load in Figure 50 must be used as the RX device when taking measurements (also see the receiver compliance eye diagram shown in Figure 49). If the clocks to the RX and TX are not derived from the same reference clock, the TX UI recovered from 3500 consecutive UI must be used as a reference for the eye diagram.
- 3. A T_{RX-EYE} = 0.40 UI provides for a total sum of 0.60 UI deterministic and random jitter budget for the transmitter and interconnect collected any 250 consecutive UIs. The T_{RX-EYE-MEDIAN-to-MAX-JITTER} specification ensures a jitter distribution in which the median and the maximum deviation from the median is less than half of the total. UI jitter budget collected over any 250 consecutive TX UIs. Note that the median is not the same as the mean. The jitter median describes the point in time where the number of jitter points on either side is approximately equal as opposed to the averaged time value. If the clocks to the RX and TX are not derived from the same reference clock, the TX UI recovered from 3500 consecutive UI must be used as the reference for the eye diagram.
- 4. The receiver input impedance shall result in a differential return loss greater than or equal to 15 dB with the D+ line biased to 300 mV and the D– line biased to $-{300 \text{ mV}}$ and a common mode return loss greater than or equal to 6 dB (no bias required) over a frequency range of 50 MHz to 1.25 GHz. This input impedance requirement applies to all valid input levels. The reference impedance for return loss measurements for is 50 Ω to ground for both the D+ and D– line (that is, as measured by a vector network analyzer with 50- Ω probes—see Figure 50). Note: that the series capacitors CTX is optional for the return loss measurement.
- 5. Impedance during all LTSSM states. When transitioning from a fundamental reset to detect (the initial state of the LTSSM) there is a 5 ms transition time before receiver termination values must be met on all unconfigured lanes of a port.
- 6. The RX DC common mode Impedance that exists when no power is present or fundamental reset is asserted. This helps ensure that the receiver detect circuit does not falsely assume a receiver is powered on when it is not. This term must be measured at 300 mV above the RX ground.
- 7. It is recommended that the recovered TX UI is calculated using all edges in the 3500 consecutive UI interval with a fit algorithm using a minimization merit function. Least squares and median deviation fits have worked well with experimental and simulated data.

17.5 Receiver Compliance Eye Diagrams

The RX eye diagram in Figure 49 is specified using the passive compliance/test measurement load (see Figure 50) in place of any real PCI Express RX component.

Note: In general, the minimum receiver eye diagram measured with the compliance/test measurement load (see Figure 50) is larger than the minimum receiver eye diagram measured over a range of systems at the input receiver of any real PCI Express component. The degraded eye diagram at the input receiver is due to traces internal to the package as well as silicon parasitic characteristics which cause the real PCI Express component to vary in impedance from the compliance/test measurement load. The input receiver eye diagram is implementation specific and is not specified. RX component designer must provide additional margin to adequately compensate for the degraded minimum receiver eye diagram (shown in Figure 49) expected at the input receiver based on some adequate combination of system simulations and the return loss measured looking into the RX package and silicon. The RX eye diagram must be aligned in time using the jitter median to locate the center of the eye diagram.

Serial RapidIO

802.3ae-2002 is specified as the test pattern for use in eye pattern and jitter measurements. Annex 48B of IEEE Std. 802.3ae-2002 is recommended as a reference for additional information on jitter test methods.

18.9.1 Eye Template Measurements

For the purpose of eye template measurements, the effects of a single-pole high pass filter with a 3 dB point at (baud frequency)/1667 is applied to the jitter. The data pattern for template measurements is the continuous jitter test pattern (CJPAT) defined in Annex 48A of IEEE 802.3ae. All lanes of the LP-serial link shall be active in both the transmit and receive directions, and opposite ends of the links shall use asynchronous clocks. Four lane implementations shall use CJPAT as defined in Annex 48A. Single lane implementations shall use the CJPAT sequence specified in Annex 48A for transmission on lane 0. The amount of data represented in the eye shall be adequate to ensure that the bit error ratio is less than 10^{-12} . The eye pattern shall be measured with AC coupling and the compliance template centered at 0 V differential. The left and right edges of the template shall be aligned with the mean zero crossing points of the measured data eye. The load for this test shall be $100-\Omega$ resistive $\pm 5\%$ differential to 2.5 GHz.

18.9.2 Jitter Test Measurements

For the purpose of jitter measurement, the effects of a single-pole high pass filter with a 3 dB point at (baud frequency)/1667 is applied to the jitter. The data pattern for jitter measurements is the Continuous Jitter test pattern (CJPAT) pattern defined in Annex 48A of IEEE 802.3ae. All lanes of the LP-serial link shall be active in both the transmit and receive directions, and opposite ends of the links shall use asynchronous clocks. Four lane implementations shall use CJPAT as defined in Annex 48A. Single lane implementations shall use the CJPAT sequence specified in Annex 48A for transmission on lane 0. Jitter shall be measured with AC coupling and at 0 V differential. Jitter measurement for the transmitter (or for calibration of a jitter tolerance setup) shall be performed with a test procedure resulting in a BER curve such as that described in Annex 48B of IEEE 802.3ae.

18.9.3 Transmit Jitter

Transmit jitter is measured at the driver output when terminated into a load of 100 Ω resistive ± 5% differential to 2.5 GHz.

18.9.4 Jitter Tolerance

Jitter tolerance is measured at the receiver using a jitter tolerance test signal. This signal is obtained by first producing the sum of deterministic and random jitter defined in Section 18.7, "Receiver Specifications," and then adjusting the signal amplitude until the data eye contacts the 6 points of the minimum eye opening of the receive template shown in Figure 54 and Table 69. Note that for this to occur, the test signal must have vertical waveform symmetry about the average value and have horizontal symmetry (including jitter) about the mean zero crossing. Eye template measurement requirements are as defined above. Random jitter is calibrated using a high pass filter with a low frequency corner at 20 MHz and a 20 dB/decade roll-off below this. The required sinusoidal jitter specified in Section 18.7, "Receiver Specifications," is then added to the signal and the test load is replaced by the receiver being tested.

Package Description

Signal	Pin Type	Power Supply	Notes	
LSYNC_IN	LSYNC_IN F27		BV _{DD}	_
LSYNC_OUT	F28	0	BV _{DD}	_
	DMA			
DMA_DACK[0:1]	AD3, AE1	0	OV _{DD}	5, 9, 102
DMA_DREQ[0:1]	AD4, AE2	ļ	OV _{DD}	—
DMA_DDONE[0:1]	AD2, AD1	0	OV _{DD}	_
	Programmable Interrupt Controller		I	
UDE	AH16	I	OV _{DD}	—
MCP	AG19	ļ	OV _{DD}	—
IRQ[0:7]	AG23, AF18, AE18, AF20, AG18, AF17, AH24, AE20	I	OV _{DD}	—
IRQ[8]	AF19	I	OV _{DD}	—
IRQ[9]/DMA_DREQ3	AF21	I	OV _{DD}	1
IRQ[10]/DMA_DACK3	AE19	I/O	OV _{DD}	1
IRQ[11]/DMA_DDONE3	AD20	I/O	OV _{DD}	1
IRQ_OUT	AD18	0	OV _{DD}	2, 4
	Ethernet Management Interface			
EC_MDC	AB9	0	OV _{DD}	5, 9
EC_MDIO	AC8 I/O		OV _{DD}	—
	Gigabit Reference Clock			
EC_GTX_CLK125	V11	I		—
Th	ree-Speed Ethernet Controller (Gigabit Ethern	et 1)		
TSEC1_RXD[7:0]	R5, U1, R3, U2, V3, V1, T3, T2	I	LV _{DD}	—
TSEC1_TXD[7:0]	T10, V7, U10, U5, U4, V6, T5, T8	0	LV _{DD}	5, 9
TSEC1_COL	R4	I	LV _{DD}	—
TSEC1_CRS	TSEC1_CRS V5		LV _{DD}	20
TSEC1_GTX_CLK	TSEC1_GTX_CLK U7		LV _{DD}	—
TSEC1_RX_CLK	TSEC1_RX_CLK U3		LV _{DD}	—
TSEC1_RX_DV	TSEC1_RX_DV V2		LV _{DD}	—
TSEC1_RX_ER	TSEC1_RX_ER T1		LV _{DD}	—
TSEC1_TX_CLK	T6	I	LV _{DD}	—
TSEC1_TX_EN	TSEC1_TX_EN U9		LV _{DD}	30
TSEC1_TX_ER	0	LV _{DD}	—	

Table 72 provides the pin-out listing for the MPC8547E 783 FC-PBGA package.

NOTE

All note references in the following table use the same numbers as those for Table 71. See Table 71 for the meanings of these notes.

Signal	Signal Package Pin Number					
PCI1 (One 64-Bit or One 32-Bit)						
PCI1_AD[63:32]	AB14, AC15, AA15, Y16, W16, AB16, AC16, AA16, AE17, AA18, W18, AC17, AD16, AE16, Y17, AC18, AB18, AA19, AB19, AB21, AA20, AC20, AB20, AB22, AC22, AD21, AB23, AF23, AD23, AE23, AC23, AC24	I/O	OV _{DD}	17		
PCI1_AD[31:0]	AH6, AE7, AF7, AG7, AH7, AF8, AH8, AE9, AH9, AC10, AB10, AD10, AG10, AA10, AH10, AA11, AB12, AE12, AG12, AH12, AB13, AA12, AC13, AE13, Y14, W13, AG13, V14, AH13, AC14, Y15, AB15	I/O	OV _{DD}	17		
PCI1_C_BE[7:4]	AF15, AD14, AE15, AD15	I/O	OV _{DD}	17		
PCI1_C_BE[3:0]	AF9, AD11, Y12, Y13	I/O	OV _{DD}	17		
PCI1_PAR64	W15	I/O	OV _{DD}	—		
PCI1_GNT[4:1]	AG6, AE6, AF5, AH5	0	OV _{DD}	5, 9, 35		
PCI1_GNT0	AG5	I/O	OV _{DD}	—		
PCI1_IRDY	AF11	I/O	OV _{DD}	2		
PCI1_PAR	AD12	I/O	OV _{DD}	—		
PCI1_PERR	AC12	I/O	OV _{DD}	2		
PCI1_SERR	V13		OV _{DD}	2, 4		
PCI1_STOP	W12	I/O	OV _{DD}	2		
PCI1_TRDY	AG11	I/O	OV _{DD}	2		
PCI1_REQ[4:1]	:1] AH2, AG4, AG3, AH4		OV _{DD}	—		
PCI1_REQ0	AH3	I/O	OV _{DD}	—		
PCI1_CLK	AH26	I	OV _{DD}	39		
PCI1_DEVSEL	AH11	I/O	OV _{DD}	2		
PCI1_FRAME	AE11	I/O	OV _{DD}	2		
PCI1_IDSEL	AG9	I	OV _{DD}	—		
PCI1_REQ64	AF14	I/O	OV _{DD}	2, 5,10		
PCI1_ACK64	V15	I/O	OV _{DD}	2		
Reserved	AE28	—	—	2		
Reserved	AD26	—	—	2		
Reserved AD25			—	2		

Table 72. MPC8547E Pinout Listing

Package Description

Table 73. MPC8545E Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
PCI1_FRAME	AE11	I/O	OV _{DD}	2
PCI1_IDSEL	AG9	I	OV _{DD}	_
PCI1_REQ64/PCI2_FRAME	AF14	I/O	OV _{DD}	2, 5, 10
PCI1_ACK64/PCI2_DEVSEL	V15	I/O	OV _{DD}	2
PCI2_CLK	AE28	I	OV _{DD}	39
PCI2_IRDY	AD26	I/O	OV _{DD}	2
PCI2_PERR	AD25	I/O	OV _{DD}	2
PCI2_GNT[4:1]	AE26, AG24, AF25, AE25	0	OV _{DD}	5, 9, 35
PCI2_GNT0	AG25	I/O	OV _{DD}	_
PCI2_SERR	AD24	I/O	OV _{DD}	2,4
PCI2_STOP	AF24	I/O	OV _{DD}	2
PCI2_TRDY	AD27	I/O	OV _{DD}	2
PCI2_REQ[4:1]	AD28, AE27, W17, AF26	I	OV _{DD}	_
PCI2_REQ0	AH25	I/O	OV _{DD}	_
	DDR SDRAM Memory Interface			
MDQ[0:63]	L18, J18, K14, L13, L19, M18, L15, L14, A17, B17, A13, B12, C18, B18, B13, A12, H18, F18, J14, F15, K19, J19, H16, K15, D17, G16, K13, D14, D18, F17, F14, E14, A7, A6, D5, A4, C8, D7, B5, B4, A2, B1, D1, E4, A3, B2, D2, E3, F3, G4, J5, K5, F6, G5, J6, K4, J1, K2, M5, M3, J3, J2, L1, M6	I/O	GV _{DD}	
MECC[0:7]	H13, F13, F11, C11, J13, G13, D12, M12	I/O	GV _{DD}	—
MDM[0:8]	M17, C16, K17, E16, B6, C4, H4, K1, E13	0	GV _{DD}	_
MDQS[0:8]	M15, A16, G17, G14, A5, D3, H1, L2, C13	I/O	GV _{DD}	_
MDQS[0:8]	L17, B16, J16, H14, C6, C2, H3, L4, D13	I/O	GV _{DD}	_
MA[0:15]	A8, F9, D9, B9, A9, L10, M10, H10, K10, G10, B8, E10, B10, G6, A10, L11	Ο	GV _{DD}	—
MBA[0:2]	F7, J7, M11	0	GV _{DD}	_
MWE	E7	0	GV _{DD}	_
MCAS	H7	0	GV _{DD}	_
MRAS	L8	0	GV _{DD}	_
MCKE[0:3]	F10, C10, J11, H11	F10, C10, J11, H11 O		11
MCS[0:3]	K8, J8, G8, F8	0	GV _{DD}	_
MCK[0:5]	H9, B15, G2, M9, A14, F1	0	GV _{DD}	_
MCK[0:5]	J9, A15, G1, L9, B14, F2	O GV _{DD}		_
MODT[0:3]	E6, K6, L7, M7	0	GV _{DD}	—

Signal	Package Pin Number	Pin Type	Power Supply	Notes
TDO	AF28	0	OV _{DD}	—
TMS	AH27	I	OV _{DD}	12
TRST	AH23	I	OV _{DD}	12
	DFT			
L1_TSTCLK	AC25	I	OV _{DD}	25
L2_TSTCLK	AE22	I	OV _{DD}	25
LSSD_MODE	AH20	I	OV_{DD}	25
TEST_SEL	AH14	I	OV _{DD}	25
	Thermal Management			
THERM0	AG1	—	_	14
THERM1	AH1	_	_	14
	Power Management			
ASLEEP	AH18	0	OV _{DD}	9, 19, 29
	Power and Ground Signals			
GND	 A11, B7, B24, C1, C3, C5, C12, C15, C26, D8, D11, D16, D20, D22, E1, E5, E9, E12, E15, E17, F4, F26, G12, G15, G18, G21, G24, H2, H6, H8, H28, J4, J12, J15, J17, J27, K7, K9, K11, K27, L3, L5, L12, L16, N11, N13, N15, N17, N19, P4, P9, P12, P14, P16, P18, R11, R13, R15, R17, R19, T4, T12, T14, T16, T18, U8, U11, U13, U15, U17, U19, V4, V12, V18, W6, W19, Y4, Y9, Y11, Y19, AA6, AA14, AA17, AA22, AA23, AB4, AC2, AC11, AC19, AC26, AD5, AD9, AD22, AE3, AE14, AF6, AF10, AF13, AG8, AG27, K28, L24, L26, N24, N27, P25, R28, T24, T26, U24, V25, W28, Y24, Y26, AA24, AA27, AB25, AC28, L21, L23, N22, P20, R23, T21, U22, V20, W23, Y21, U27 			
OV _{DD}	V16, W11, W14, Y18, AA13, AA21, AB11, AB17, AB24, AC4, AC9, AC21, AD6, AD13, AD17, AD19, AE10, AE8, AE24, AF4, AF12, AF22, AF27, AG26	Power for PCI and other standards (3.3 V)	OV _{DD}	_
LV _{DD}	N8, R7, T9, U6	Power for TSEC1 and TSEC2 (2.5 V, 3.3 V)	LV _{DD}	_
TV _{DD}	TV _{DD} W9, Y6		TV _{DD}	

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GPOUT[0:5]	N9, N10, P8, N7, R9, N5	0	LV _{DD}	—
cfg_dram_type0/GPOUT6	R8	0	LV _{DD}	5, 9
GPOUT7	N6	0	LV _{DD}	—
Reserved	P1		_	104
Reserved	R6	—	_	104
Reserved	P6		_	15
Reserved	N4	—	_	105
FIFO1_RXC2	P5	I	LV _{DD}	104
Reserved	R1	—	_	104
Reserved	P10	—	_	105
FIFO1_TXC2	P7	0	LV _{DD}	15
cfg_dram_type1	R10	0	LV _{DD}	5, 9
Thr	ee-Speed Ethernet Controller (Gigabit I	Ethernet 3)		
TSEC3_TXD[3:0]	V8, W10, Y10, W7	0	TV _{DD}	5, 9, 29
TSEC3_RXD[3:0]	Y1, W3, W5, W4	I	TV _{DD}	_
TSEC3_GTX_CLK	W8	0	TV _{DD}	_
TSEC3_RX_CLK	W2	I	TV _{DD}	_
TSEC3_RX_DV	W1	I	TV _{DD}	_
TSEC3_RX_ER	Y2	I	TV _{DD}	_
TSEC3_TX_CLK	V10	I	TV _{DD}	—
TSEC3_TX_EN	V9	0	TV _{DD}	30
TSEC3_TXD[7:4]	AB8, Y7, AA7, Y8	0	TV _{DD}	5, 9, 29
TSEC3_RXD[7:4]	AA1, Y3, AA2, AA4	I	TV _{DD}	_
Reserved	AA5	—	—	15
TSEC3_COL	Y5	I	TV _{DD}	—
TSEC3_CRS	AA3	I/O	TV _{DD}	31
TSEC3_TX_ER	AB6	0	TV _{DD}	—
	DUART	1		
UART_CTS[0:1]	AB3, AC5	I	OV _{DD}	_
UART_RTS[0:1]	AC6, AD7	0	OV _{DD}	—
UART_SIN[0:1]	AB5, AC7	I	OV _{DD}	_
UART_SOUT[0:1]	AB7, AD8	0	OV _{DD}	—
	I ² C interface	I		
IIC1_SCL	AG22	I/O	OV _{DD}	4, 27

Table 74. MPC8543E Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes		
IIC1_SDA	AG21	I/O	OV _{DD}	4, 27		
IIC2_SCL	AG15	I/O	OV _{DD}	4, 27		
IIC2_SDA	AG14	I/O	OV _{DD}	4, 27		
SerDes						
SD_RX[0:7]	M28, N26, P28, R26, W26, Y28, AA26, AB28	I	XV _{DD}	—		
SD_RX[0:7]	M27, N25, P27, R25, W25, Y27, AA25, AB27	I	XV _{DD}	—		
SD_TX[0:7]	M22, N20, P22, R20, U20, V22, W20, Y22	0	XV _{DD}	—		
SD_TX[0:7]	M23, N21, P23, R21, U21, V23, W21, Y23	0	XV _{DD}	—		
SD_PLL_TPD	U28	0	XV _{DD}	24		
SD_REF_CLK	T28	I	XV _{DD}	—		
SD_REF_CLK	T27	I	XV _{DD}	—		
Reserved	AC1, AC3		_	2		
Reserved	M26, V28	_	_	32		
Reserved	M25, V27	_	_	34		
Reserved	M20, M21, T22, T23 —		—	38		
	General-Purpose Output					
GPOUT[24:31]	K26, K25, H27, G28, H25, J26, K24, K23	0	BV _{DD}	—		
System Control						
HRESET	AG17	I	OV _{DD}	—		
HRESET_REQ	AG16	0	OV _{DD}	29		
SRESET	AG20	I	OV _{DD}	—		
CKSTP_IN	AA9	I	OV _{DD}	—		
CKSTP_OUT	AA8	0	OV _{DD}	2, 4		
	Debug			•		
TRIG_IN	AB2	I	OV _{DD}	—		
TRIG_OUT/READY/QUIESCE AB1		0	OV _{DD}	6, 9, 19, 29		
MSRCID[0:1]	MSRCID[0:1] AE4, AG2		OV _{DD}	5, 6, 9		
MSRCID[2:4]	ISRCID[2:4] AF3, AF1, AF2		OV _{DD}	6, 19, 29		
MDVAL	AE5	0	OV _{DD}	6		
CLK_OUT	CLK_OUT AE21		OV _{DD}	11		
Clock						
RTC	AF16	I	OV _{DD}	—		
SYSCLK	SYSCLK AH17		OV _{DD}			

- First, the board must have at least 10 × 10-nF SMT ceramic chip capacitors as close as possible to the supply balls of the device. Where the board has blind vias, these capacitors must be placed directly below the chip supply and ground connections. Where the board does not have blind vias, these capacitors must be placed in a ring around the device as close to the supply and ground connections as possible.
- Second, there must be a $1-\mu F$ ceramic chip capacitor from each SerDes supply (SV_{DD} and XV_{DD}) to the board ground plane on each side of the device. This must be done for all SerDes supplies.
- Third, between the device and any SerDes voltage regulator there must be a 10- μ F, low equivalent series resistance (ESR) SMT tantalum chip capacitor and a 100- μ F, low ESR SMT tantalum chip capacitor. This must be done for all SerDes supplies.

22.5 Connection Recommendations

To ensure reliable operation, it is highly recommended to connect unused inputs to an appropriate signal level. All unused active low inputs must be tied to V_{DD} , TV_{DD} , BV_{DD} , OV_{DD} , GV_{DD} , and LV_{DD} , as required. All unused active high inputs must be connected to GND. All NC (no-connect) signals must remain unconnected. Power and ground connections must be made to all external V_{DD} , TV_{DD} , BV_{DD} , OV_{DD} , GV_{DD} , TV_{DD} , BV_{DD} , OV_{DD} , GV_{DD} , LV_{DD} , and GND pins of the device.

22.6 Pull-Up and Pull-Down Resistor Requirements

The device requires weak pull-up resistors (2–10 k Ω is recommended) on open drain type pins including I²C pins and PIC (interrupt) pins.

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 63. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions as most have asynchronous behavior and spurious assertion gives unpredictable results.

The following pins must not be pulled down during power-on reset: TSEC3_TXD[3], HRESET_REQ, TRIG_OUT/READY/QUIESCE, MSRCID[2:4], ASLEEP. The DMA_DACK[0:1], and TEST_SEL/TEST_SEL pins must be set to a proper state during POR configuration. See the pinlist table of the individual device for more details

See the PCI 2.2 specification for all pull ups required for PCI.

22.7 Output Buffer DC Impedance

The device drivers are characterized over process, voltage, and temperature. For all buses, the driver is a push-pull single-ended driver type (open drain for I^2C).

To measure Z_0 for the single-ended drivers, an external resistor is connected from the chip pad to OV_{DD} or GND. Then, the value of each resistor is varied until the pad voltage is $OV_{DD}/2$ (see Figure 61). The output impedance is the average of two components, the resistances of the pull-up and pull-down devices. When data is held high, SW1 is closed (SW2 is open) and R_P is trimmed until the voltage at the pad equals $OV_{DD}/2$. R_P then becomes the resistance of the pull-up devices. R_P and R_N are designed to be close to each other in value. Then, $Z_0 = (R_P + R_N)/2$.

System Design Information

The platform PLL ratio and e500 PLL ratio configuration pins are not equipped with these default pull-up devices.

22.9 JTAG Configuration Signals

Correct operation of the JTAG interface requires configuration of a group of system control pins as demonstrated in Figure 63. Care must be taken to ensure that these pins are maintained at a valid deasserted state under normal operating conditions as most have asynchronous behavior and spurious assertion gives unpredictable results.

Boundary-scan testing is enabled through the JTAG interface signals. The TRST signal is optional in the IEEE 1149.1 specification, but it is provided on all processors built on Power Architecture technology. The device requires TRST to be asserted during power-on reset flow to ensure that the JTAG boundary logic does not interfere with normal chip operation. While the TAP controller can be forced to the reset state using only the TCK and TMS signals, generally systems assert TRST during the power-on reset flow. Simply tying TRST to HRESET is not practical because the JTAG interface is also used for accessing the common on-chip processor (COP), which implements the debug interface to the chip.

The COP function of these processors allow a remote computer system (typically, a PC with dedicated hardware and debugging software) to access and control the internal operations of the processor. The COP interface connects primarily through the JTAG port of the processor, with some additional status monitoring signals. The COP port requires the ability to independently assert HRESET or TRST in order to fully control the processor. If the target system has independent reset sources, such as voltage monitors, watchdog timers, power supply failures, or push-button switches, then the COP reset signals must be merged into these signals with logic.

The arrangement shown in Figure 63 allows the COP port to independently assert $\overline{\text{HRESET}}$ or $\overline{\text{TRST}}$, while ensuring that the target can drive $\overline{\text{HRESET}}$ as well.

The COP interface has a standard header, shown in Figure 62, for connection to the target system, and is based on the 0.025" square-post, 0.100" centered header assembly (often called a Berg header). The connector typically has pin 14 removed as a connector key.

The COP header adds many benefits such as breakpoints, watchpoints, register and memory examination/modification, and other standard debugger features. An inexpensive option can be to leave the COP header unpopulated until needed.

There is no standardized way to number the COP header; so emulator vendors have issued many different pin numbering schemes. Some COP headers are numbered top-to-bottom then left-to-right, while others use left-to-right then top-to-bottom. Still others number the pins counter-clockwise from pin 1 (as with an IC). Regardless of the numbering scheme, the signal placement recommended in Figure 62 is common to all known emulators.

22.9.1 Termination of Unused Signals

Freescale recommends the following connections, when the JTAG interface and COP header are not used:

• TRST must be tied to HRESET through a 0 k Ω isolation resistor so that it is asserted when the system reset signal (HRESET) is asserted, ensuring that the JTAG scan chain is initialized during the power-on reset flow. Freescale recommends that the COP header be designed into the system

Ordering Information

MPC	nnnnn	t	рр	ff	C	r
Product Code	Part Identifier	Temperature	Package ^{1, 2, 3}	Processor Frequency ⁴	Core Frequency	Silicon Version
MPC	8545E	Blank = 0 to 105°C C = -40° to 105°C	HX = CBGA VU = Pb-free CBGA PX = PBGA VT = Pb-free PBGA	AT = 1200 AQ = 1000 AN = 800	G = 400	Blank = Ver. 2.0 (SVR = 0x80390220) A = Ver. 2.1.1 B = Ver. 2.1.2 D = Ver. 3.1.x (SVR = 0x80390231)
	8545					Blank = Ver. 2.0 (SVR = 0x80310220) A = Ver. 2.1.1 B = Ver. 2.1.2 D = Ver. 3.1.x (SVR = 0x80310231)
	8543E			AQ = 1000 AN = 800		Blank = Ver. 2.0 (SVR = 0x803A0020) A = Ver. 2.1.1 B = Ver. 2.1.2 D = Ver. 3.1.x (SVR = 0x803A0031)
	8543					Blank = Ver. 2.0 (SVR = 0x80320020) A = Ver. 2.1.1 B = Ver. 2.1.2 D = Ver. 3.1.x (SVR = 0x80320031)

Table 87. Part Numbering Nomenclature (continued)

Notes:

1. See Section 19, "Package Description," for more information on available package types.

2. The HiCTE FC-CBGA package is available on only Version 2.0 of the device.

3. The FC-PBGA package is available on only Version 2.1.1, 2.1.2, and 2.1.3 of the device.

- Processor core frequencies supported by parts addressed by this specification only. Not all parts described in this specification support all core frequencies. Additionally, parts addressed by part number specifications may support other maximum core frequencies.
- 5. This speed available only for silicon Version 2.1.1, 2.1.2, and 2.1.3.

23.2 Part Marking

Parts are marked as the example shown in Figure 64.



Notes:

TWLYYWW is final test traceability code. MMMMM is 5 digit mask number. CCCCC is the country of assembly. This space is left blank if parts are assembled in the United States. YWWLAZ is assembly traceability code.

Figure 64. Part Marking for CBGA and PBGA Device

24 Document Revision History

The following table provides a revision history for this hardware specification.

Rev. Date Substantive Change(s) Number • Updated Section 21.2, "Thermal for Version 2.1.1, 2.1.2, and 2.1.3 Silicon FC-PBGA with Full Lid and 9 02/2012 Version 3.1.x Silicon with Stamped Lid," with version 3.0 silicon information. Added Figure 56, "Mechanical Dimensions and Bottom Surface Nomenclature of the FC-PBGA with Stamped Lid." • Updated Table 87, "Part Numbering Nomenclature," with version 3.0 silicon information. Removed Note from Section 5.1. "Power-On Ramp Rate". • Changed the Table 10 title to "Power Supply Ramp Rate". • Removed table 11. • Updated the title of Section 21.2, "Thermal for Version 2.1.1, 2.1.2, and 2.1.3 Silicon FC-PBGA with Full Lid and Version 3.1.x Silicon with Stamped Lid" to include Thermal Version 2.1.3 and Version 3.1.x Silicon. Corrected the leaded Solder Ball composition in Table 70, "Package Parameters" • Updated Table 87, "Part Numbering Nomenclature," with Version 3.1.x silicon information. • Updated the Min and Max value of TDO in the valid times row of Table 44, "JTAG AC Timing Specifications (Independent of SYSCLK)¹" from 4 and 25 to 2 and 10 respectively . 8 04/2011 Added Section 14.1, "GPOUT/GPIN Electrical Characteristics." • Updated Table 71, "MPC8548E Pinout Listing," Table 72, "MPC8547E Pinout Listing," Table 73, "MPC8545E Pinout Listing," and Table 74, "MPC8543E Pinout Listing," to reflect that the TDO signal is not driven during HRSET* assertion. • Updated Table 87, "Part Numbering Nomenclature" with Ver. 2.1.3 silicon information. In Table 37, "MII Management AC Timing Specifications, modified the fifth row from "MDC to MDIO 7 09/2010 delay tMDKHDX (16 x tptb_clk x 8) - 3 - (16 x tptb_clk x 8) + 3" to "MDC to MDIO delay tMDKHDX $(16 \times tCCB \times 8) - 3 - (16 \times tCCB \times 8) + 3."$ Updated Figure 55, "Mechanical Dimensions and Bottom Surface Nomenclature of the HiCTE FC-CBGA and FC-PBGA with Full Lid and figure notes. 6 12/2009 • In Section 5.1, "Power-On Ramp Rate" added explanation that Power-On Ramp Rate is required to avoid falsely triggering ESD circuitry. In Table 13 changed required ramp rate from 545 V/s for MVREF and VDD/XVDD/SVDD to 3500 V/s for MVREF and 4000 V/s for VDD. • In Table 13 deleted ramp rate requirement for XVDD/SVDD. In Table 13 footnote 1 changed voltage range of concern from 0-400 mV to 20-500mV. In Table 13 added footnote 2 explaining that VDD voltage ramp rate is intended to control ramp rate of AVDD pins. 5 10/2009 • In Table 27, "GMII Receive AC Timing Specifications," changed duty cycle specification from 40/60 to 35/75 for RX CLK duty cycle. Updated tMDKHDX in Table 37, "MII Management AC Timing Specifications." • Added a reference to Revision 2.1.2. • Updated Table 55, "MII Management AC Timing Specifications." Added Section 5.1, "Power-On Ramp Rate."

Table 88. Document Revision History